

# isc Silicon PNP Power Transistor

2SB1054

#### **DESCRIPTION**

- · Low Collector Saturation Voltage-
  - : V<sub>CE(sat)</sub>= -2.0V(Max)@I<sub>C</sub>= -3A
- · Wide Area of Safe Operation
- Complement to Type 2SD1485
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

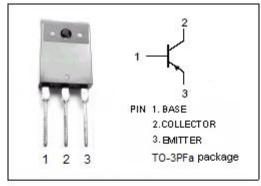


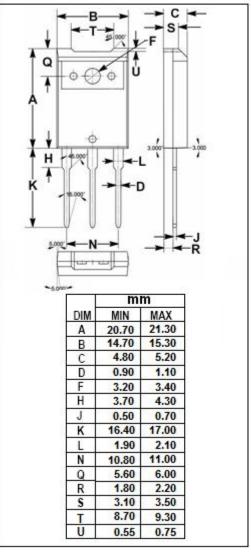
### **APPLICATIONS**

· Designed for high power amplification.



SYMBOL	PARAMETER	VALUE	UNIT	
$V_{CBO}$	Collector-Base Voltage -100		V	
V <sub>CEO</sub>	Collector-Emitter Voltage -100		V	
V <sub>EBO</sub>	Emitter-Base Voltage -5		V	
lc	Collector Current-Continuous -5		Α	
Ісм	Collector Current-Peak -8		Α	
D.	Collector Power Dissipation @ T <sub>a</sub> =25℃	3	- W	
Pc	Collector Power Dissipation @ T <sub>C</sub> =25°C	60		
Тл	Junction Temperature	150 ℃		
T <sub>stg</sub>	Storage Temperature Range -55~150		°C	







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### **ELECTRICAL CHARACTERISTICS**

 $T_c=25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -0.3A			-2.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -3A; V <sub>CE</sub> = -5V			-1.8	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -100V; I <sub>E</sub> = 0			-50	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -3V; I <sub>C</sub> = 0			-50	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -20mA; V <sub>CE</sub> = -5V	20			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	60		200	
h <sub>FE-3</sub>	DC Current Gain	I <sub>C</sub> = -3A; V <sub>CE</sub> = -5V	20			
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CE</sub> = -10V; f <sub>test</sub> =1MHz		170		pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> =-0.5A; V <sub>CE</sub> = -5V;f <sub>test</sub> =1MHz		20		MHz

## ♦ h<sub>FE-2</sub> Classifications

Q	Р
60-120	100-200

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